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SN74LVC16T245 16-BIT DUAL-SUPPLY BUS TRANSCEIVER WITH CONFIGURABLE VOLTAGE TRANSLATION AND 3-STATE OUTPUTS

SCES636A-AUGUST 2005-REVISED AUGUST 2005

FEATURES

- Control Inputs V_{IH}/V_{IL} Levels Are Referenced to V_{CCA} Voltage
- V_{CC} Isolation Feature If Either V_{CC} Input Is at GND, Both Ports Are in the High-Impedance State
- Overvoltage-Tolerant Inputs/Outputs Allow Mixed-Voltage-Mode Data Communications
- Fully Configurable Dual-Rail Design Allows Each Port to Operate Over the Full 1.65-V to 5.5-V Power-Supply Range
- I_{off} Supports Partial-Power-Down Mode Operation
- Latch-Up Performance Exceeds 100 mA Per JESD 78. Class II
- ESD Protection Exceeds JESD 22
 - 2000-V Human-Body Model (A114-A)
 - 200-V Machine Model (A115-A)
 - 1000-V Charged-Device Model (C101)

DESCRIPTION/ORDERING INFORMATION

This 16-bit noninverting bus transceiver uses two separate configurable power-supply rails. The A port is designed to track V_{CCA} . V_{CCA} accepts any supply voltage from 1.65 V to 5.5 V. The B port is designed to track V_{CCB} . V_{CCB} accepts any supply voltage from 1.65 V to 5.5 V. This allows for universal low-voltage bidirectional translation between any of the 1.8-V, 2.5-V, 3.3-V, and 5-V voltage nodes.

DGG OR DGV PACKAGE (TOP VIEW)

| | | | | , |
|-----------|----|--------|----|------------------|
| 4 D.ID [| | \cup | 40 | 1.5= |
| 1DIR L | 1 | | | 1 <u>OE</u> |
| 1B1 | 2 | | | 1A1 |
| 1B2 L | 3 | | |] 1A2 |
| GND [| 4 | | | GND |
| 1B3 [| 5 | | 44 | 1A3 |
| 1B4 [| 6 | | |] 1A4 |
| V_{CCB} | 7 | | | V _{CCA} |
| 1B5 [| 8 | | 41 | 1A5 |
| 1B6 [| 9 | | 40 |] 1A6 |
| GND [| 10 | | 39 | GND |
| 1B7 [| 11 | | 38 |] 1A7 |
| 1B8 [| 12 | | 37 |] 1A8 |
| 2B1 [| 13 | | 36 | 2A1 |
| 2B2 [| 14 | | 35 | 2A2 |
| GND [| 15 | | 34 | GND |
| 2B3 [| 16 | | 33 | 2A3 |
| 2B4 [| 17 | | 32 |] 2A4 |
| V_{CCB} | 18 | | 31 | VCCA |
| 2B5 [| 19 | | 30 | 2A5 |
| 2B6 [| 20 | | 29 | 2A6 |
| GND [| 21 | | 28 | GND |
| 2B7 [| 22 | | 27 | 2A7 |
| 2B8 [| 23 | | | 2A8 |
| 2DIR [| 24 | | 25 | 2 0E |
| | | | | |

The SN74LVC16T245 is designed for asynchronous communication between two data buses. The logic levels of the direction-control (DIR) input and the output-enable (\overline{OE}) input activate either the B-port outputs or the A-port outputs or place both output ports into the high-impedance mode. The device transmits data from the A bus to the B bus when the B-port outputs are activated, and from the B bus to the A bus when the A-port outputs are activated. The input circuitry on both A and B ports is always active and must have a logic HIGH or LOW level applied to prevent excess I_{CC} and I_{CCZ} .

The SN74LVC16T245 is designed so that the control pins (1DIR, 2DIR, 1OE, and 2OE) are supplied by V_{CCA}.

This device is fully specified for partial-power-down applications using I_{off}. The I_{off} circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

ORDERING INFORMATION

| T _A | PACKAGE ⁽¹ |) | ORDERABLE PART NUMBER | TOP-SIDE MARKING |
|----------------|-----------------------|---------------|-----------------------|------------------|
| | TSSOP – DGG | Tape and reel | SN74LVC16T245DGGR | LVC16T245 |
| 400C to 050C | TVSOP - DGV | Tape and reel | SN74LVC16T245DGVR | LDT245 |
| –40°C to 85°C | VFBGA – GQL | Tape and reel | SN74LVC16T245GQLR | LDT245 |
| | VFBGA – ZQL (Pb-free) | Tape and reel | SN74LVC16T245ZQLR | PREVIEW |

(1) Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

TEXAS INSTRUMENTS WWW.ti.com

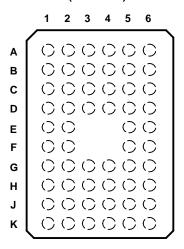
SCES636A-AUGUST 2005-REVISED AUGUST 2005

DESCRIPTION/ORDERING INFORMATION (CONTINUED)

The V_{CC} isolation feature ensures that if either V_{CC} input is at GND, then both ports are in the high-impedance state.

To ensure the high-impedance state during power up or power down, \overline{OE} should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

GQL OR ZQL PACKAGE (TOP VIEW)



TERMINAL ASSIGNMENTS(1)

| | 1 | 2 | 3 | 4 | 5 | 6 |
|---|------|-----|-----------|-----------|-----|-----------------|
| Α | 1DIR | NC | NC | NC | NC | 1 OE |
| В | 1B2 | 1B1 | GND | GND | 1A1 | 1A2 |
| С | 1B4 | 1B3 | V_{CCB} | V_{CCA} | 1A3 | 1A4 |
| D | 1B6 | 1B5 | GND | GND | 1A5 | 1A6 |
| E | 1B8 | 1B7 | | | 1A7 | 1A8 |
| F | 2B1 | 2B2 | | | 2A2 | 2A1 |
| G | 2B3 | 2B4 | GND | GND | 2A4 | 2A3 |
| Н | 2B5 | 2B6 | V_{CCB} | V_{CCA} | 2A6 | 2A5 |
| J | 2B7 | 2B8 | GND | GND | 2A8 | 2A7 |
| K | 2DIR | NC | NC | NC | NC | 2 OE |

(1) NC - No internal connection

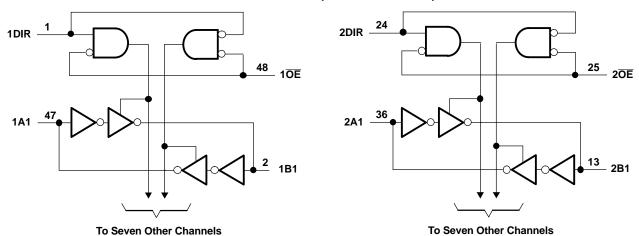
FUNCTION TABLE⁽¹⁾ (EACH 16-BIT SECTION)

| CONTRO | L INPUTS | OUTPUT C | IRCUITS | OPERATION |
|--------|----------|----------|---------|-----------------|
| ŌĒ | DIR | A PORT | B PORT | OPERATION |
| L | L | Enabled | Hi-Z | B data to A bus |
| L | Н | Hi-Z | Enabled | A data to B bus |
| Н | Χ | Hi-Z | Hi-Z | Isolation |

(1) Input circuits of the data I/Os always are active.

SCES636A-AUGUST 2005-REVISED AUGUST 2005

LOGIC DIAGRAM (POSITIVE LOGIC)



Absolute Maximum Ratings(1)

over operating free-air temperature range (unless otherwise noted)

| | | | MIN | MAX | UNIT |
|-------------------|--|--------------------|---------------------------|------------------------|------|
| $V_{CCA} V_{CCB}$ | Supply voltage range | | -0.5 | 6.5 | V |
| | | I/O ports (A port) | -0.5 | 6.5 | |
| VI | Input voltage range (2) | I/O ports (B port) | -0.5 | 6.5 | V |
| | | Control inputs | -0.5 | 6.5 | |
| \/ | Voltage range applied to any output | A port | -0.5 | 6.5 | V |
| Vo | in the high-impedance or power-off state (2) | B port | -0.5 | 6.5 | V |
| \ / | Valence and a second of the se | A port | -0.5 V _{CCA} + 0 | | V |
| Vo | Voltage range applied to any output in the high or low state (2)(3) | B port | | V _{CCB} + 0.5 | V |
| I _{IK} | Input clamp current | V _I < 0 | | - 50 | mA |
| I _{OK} | Output clamp current | V _O < 0 | | - 50 | mA |
| Io | Continuous output current | · | | ±50 | mA |
| | Continuous current through each V _{CCA} , V _{CCB} , and GND | | | ±100 | mA |
| | | DGG package | | 70 | |
| θ_{JA} | Package thermal impedance (4) | DGV package | | 58 | °C/W |
| | | GQL/ZQL package | | 28 | |
| T _{stg} | Storage temperature range | | -65 | 150 | °C |

⁽¹⁾ Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

⁽²⁾ The input and output negative-voltage ratings may be exceeded if the input and output current ratings are observed.

⁽³⁾ The output positive-voltage rating may be exceeded up to 6.5 V maximum if the output current rating is observed.

⁽⁴⁾ The package thermal impedance is calculated in accordance with JESD 51-7.



SCES636A-AUGUST 2005-REVISED AUGUST 2005

Recommended Operating Conditions (1)(2)(3)(4)

| | | | V _{CCI} | V _{cco} | MIN | MAX | UNIT |
|-----------------|----------------------------|--|------------------|------------------|-----------------------|-----------------------|------|
| V_{CCA} | Supply voltage | | | | 1.65 | 5.5 | V |
| V_{CCB} | Supply voltage | | | | 1.65 | 5.5 | V |
| | | | 1.65 V to 1.95 V | | $V_{CCI} \times 0.65$ | | |
| ., | High-level | D-1- ' (5) | 2.3 V to 2.7 V | | 1.7 | | ., |
| V_{IH} | input voltage | Data inputs (5) | 3 V to 3.6 V | | 2 | | V |
| | | | 4.5 V to 5.5 V | | $V_{CCI} \times 0.7$ | | |
| | | | 1.65 V to 1.95 V | | | $V_{CCI} \times 0.35$ | |
| \ / | Low-level | Data innuta (5) | 2.3 V to 2.7 V | | | 0.7 | V |
| V_{IL} | input voltage | Data inputs (5) | 3 V to 3.6 V | | | 0.8 | V |
| | | | 4.5 V to 5.5 V | | | $V_{CCI} \times 0.3$ | |
| | | | 1.65 V to 1.95 V | | $V_{CCA} \times 0.65$ | | |
| ., | High-level | Control inputs | 2.3 V to 2.7 V | | 1.7 | | ., |
| V_{IH} | input voltage | (referenced to V _{CCA}) ⁽⁶⁾ | 3 V to 3.6 V | | 2 | | V |
| | | | 4.5 V to 5.5 V | | $V_{CCA} \times 0.7$ | | |
| | | | 1.65 V to 1.95 V | | | $V_{CCA} \times 0.35$ | |
| ., | Low-level | Control inputs | 2.3 V to 2.7 V | | | 0.7 | ., |
| V_{IL} | input voltage | (referenced to V _{CCA}) ⁽⁶⁾ | 3 V to 3.6 V | | | 0.8 | V |
| | | | 4.5 V to 5.5 V | | | $V_{CCA} \times 0.3$ | |
| VI | Input voltage | Control inputs | | | 0 | 5.5 | V |
| ., | land the death and the sec | Active state | | | 0 | V _{cco} | V |
| $V_{I/O}$ | Input/output voltage | 3-State | | | 0 | 5.5 | V |
| | | | | 1.65 V to 1.95 V | | -4 | |
| | I limb lavel autout aven | | | 2.3 V to 2.7 V | | -8 | A |
| I _{OH} | High-level output curre | ent. | | 3 V to 3.6 V | | -24 | mA |
| | | | | 4.5 V to 5.5 V | | -32 | |
| | | | | 1.65 V to 1.95 V | | 4 | |
| | Laurianal autout arma | | | 2.3 V to 2.7 V | | 8 | A |
| I _{OL} | Low-level output curre | nt | | 3 V to 3.6 V | | 24 | mA |
| | | | | 4.5 V to 5.5 V | | 32 | |
| | | | 1.65 V to 1.95 V | | | 20 | |
| A 4 / 4 | Input transition | Data innuts | 2.3 V to 2.7 V | | | 20 | 01 |
| Δt/Δv | rise or fall rate | Data inputs | 3 V to 3.6 V | | | 10 | ns/V |
| | | | 4.5 V to 5.5 V | | | 5 | |
| T _A | Operating free-air tem | perature | | | -40 | 85 | °C |

⁽¹⁾ V_{CCI} is the V_{CC} associated with the data input port. (2) V_{CCO} is the V_{CC} associated with the output port.

All unused or driven (floating) data inputs (I/Os) of the device must be held at logic HIGH or LOW (preferably V_{CCI} or GND) to ensure proper device operation and minimize power. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

 ⁽⁴⁾ All unused data inputs of the device must be held at V_{CCA} or GND to ensure proper device operation.
 (5) For V_{CCI} values not specified in the data sheet, V_{IH} min = V_{CCI} × 0.7 V, V_{IL} max = V_{CCI} × 0.3 V.
 (6) For V_{CCA} values not specified in the data sheet, V_{IH} min = V_{CCA} × 0.7 V, V_{IL} max = V_{CCA} × 0.3 V.



SCES636A-AUGUST 2005-REVISED AUGUST 2005

Electrical Characteristics (1)(2)

over recommended operating free-air temperature range (unless otherwise noted)

| DAD | AMETER | TEST CONDITIONS | V | V | $T_A = 25^{\circ}C$ | –40°C to 85°C | UNIT |
|-----------------------------------|----------------|--|------------------|------------------|---------------------|------------------------|------|
| PAR | AMETER | TEST CONDITIONS | V _{CCA} | V _{CCB} | MIN TYP MAX | MIN MAX | UNII |
| | | $I_{OH} = -100 \mu\text{A}, \qquad V_I = V_{IH}$ | 1.65 V to 4.5 V | 1.65 V to 4.5 V | | V _{CCO} - 0.1 | |
| | | $I_{OH} = -4 \text{ mA}, \qquad V_I = V_{IH}$ | 1.65 V | 1.65 V | | 1.2 | |
| V_{OH} | | $I_{OH} = -8 \text{ mA}, \qquad V_I = V_{IH}$ | 2.3 V | 2.3 V | | 1.9 | V |
| | | $I_{OH} = -24 \text{ mA}, V_I = V_{IH}$ | 3 V | 3 V | | 2.4 | |
| | | $I_{OH} = -32 \text{ mA}, V_I = V_{IH}$ | 4.5 V | 4.5 V | | 3.8 | |
| | | $I_{OL} = 100 \mu A, \qquad V_I = V_{IL}$ | 1.65 V to 4.5 V | 1.65 V to 4.5 V | | 0.1 | |
| | | $I_{OL} = 4 \text{ mA}, \qquad V_I = V_{IL}$ | 1.65 V | 1.65 V | | 0.45 | |
| V_{OL} | | $I_{OL} = 8 \text{ mA}, \qquad V_I = V_{IL}$ | 2.3 V | 2.3 V | | 0.3 | V |
| | | $I_{OL} = 24 \text{ mA}, \qquad V_I = V_{IL}$ | 3 V | 3 V | | 0.55 | |
| | | $I_{OL} = 32 \text{ mA}, \qquad V_I = V_{IL}$ | 4.5 V | 4.5 V | | 0.55 | |
| l _l | Control inputs | V _I = V _{CCA} or GND | 1.65 V to 5.5 V | 1.65 V to 5.5 V | ±1 | ±2 | μΑ |
| | A or B | V V 0 (- 5 5 V | 0 V | 0 to 5.5 V | ±1 | ±2 | ^ |
| off | port | V_I or $V_O = 0$ to 5.5 V | 0 to 5.5 V | 0 V | ±1 | ±2 | μΑ |
| oz | A or B port | $\frac{V_O}{OE} = V_{CCO}$ or GND, $\frac{V_O}{OE} = V_{IH}$ | 1.65 V to 5.5 V | 1.65 V to 5.5 V | ±1 | ±2 | μΑ |
| | - 11 | | 1.65 V to 5.5 V | 1.65 V to 5.5 V | | 20 | |
| I _{CCA} | | $V_I = V_{CCI}$ or GND, $I_O = 0$ | 5 V | 0 V | | 20 | μΑ |
| | | 10 - 0 | 0 V | 5 V | | -2 | |
| | | | 1.65 V to 5.5 V | 1.65 V to 5.5 V | | 20 | |
| І _{ссв} | | $V_I = V_{CCI}$ or GND, $I_O = 0$ | 5 V | 0 V | | -2 | μΑ |
| | | 10 - 0 | 0 V | 5 V | | 20 | |
| I _{CCA} + I ₀ | ССВ | $V_I = V_{CCI}$ or GND, $I_O = 0$ | 1.65 V to 5.5 V | 1.65 V to 5.5 V | | 30 | μΑ |
| | A port | One A port at V _{CCA} – 0.6 V, DIR at V _{CCA} , B port = open | | | | 50 | |
| ΔI _{CCA} | DIR | DIR at $V_{CCA} - 0.6 \text{ V}$, B port = open, A port at V_{CCA} or GND | 3 V to 5.5 V | 3 V to 5.5 V | | 50 | μА |
| Δl _{CCB} | B port | One B port at V _{CCB} – 0.6 V, DIR at GND, A port = open | 3 V to 5.5 V | 3 V to 5.5 V | | 50 | μΑ |
| C _i | Control inputs | V _I = V _{CCA} or GND | 3.3 V | 3.3 V | 4 | 5 | pF |
| C _{io} | A or B port | $V_O = V_{CCA/B}$ or GND | 3.3 V | 3.3 V | 8.5 | 10 | pF |

 $[\]begin{array}{ll} \hbox{(1)} & V_{CCO} \text{ is the } V_{CC} \text{ associated with the output port.} \\ \hbox{(2)} & V_{CCI} \text{ is the } V_{CC} \text{ associated with the input port.} \\ \end{array}$



SCES636A-AUGUST 2005-REVISED AUGUST 2005

Switching Characteristics

over recommended operating free-air temperature range, V_{CCA} = 1.8 V \pm 0.15 V (unless otherwise noted) (see Figure 1)

| PARAMETER | FROM (INPUT) | TO (OUTPUT) | V _{CCB} = ± 0.1 | 1.8 V 5 V | V _{CCB} = ± 0.2 | | V _{CCB} = ± 0.3 | | V _{CCB} = ± 0.5 | | UNIT |
|------------------|-----------------|----------------|-----------------------------|--------------|-----------------------------|------|-----------------------------|------|-----------------------------|------|------|
| | (INPOT) | (001701) | MIN | MAX | MIN | MAX | MIN | MAX | MIN | MAX | |
| t _{PLH} | А | В | 1.7 | 21.9 | 1.3 | 9.2 | 1 | 7.4 | 0.8 | 7.1 | ns |
| t _{PHL} | ^ | В | 1.7 | 21.5 | 1.5 | 3.2 | | 7.4 | 0.0 | 7.1 | 113 |
| t _{PLH} | В | А | 0.9 | 23.8 | 0.8 | 23.6 | 0.7 | 23.4 | 0.7 | 23.4 | ns |
| t _{PHL} | Ь | Λ | 0.9 | 25.0 | 0.0 | 25.0 | 0.7 | 25.4 | 0.7 | 25.4 | 113 |
| t _{PHZ} | ŌĒ | A | 1.6 | 29.6 | 1.5 | 29.4 | 1.5 | 29.3 | 1.4 | 29.2 | ns |
| t _{PLZ} | OL | A | 1.0 | 29.0 | 1.5 | 29.4 | 1.5 | 29.3 | 1.4 | 29.2 | 115 |
| t _{PHZ} | ŌĒ | В | 2.4 | 32.2 | 1.9 | 13.1 | 1.7 | 12 | 1.3 | 10.3 | ns |
| t _{PLZ} | OL | В | 2.4 | 52.2 | 1.3 | 13.1 | 1.7 | 12 | 1.5 | 10.5 | 113 |
| t _{PZH} | ŌĒ | Α | 0.4 | 24 | 0.4 | 23.8 | 0.4 | 23.7 | 0.4 | 23.7 | ns |
| t _{PZL} | OL | Α | 0.4 | 24 | 0.4 | 23.0 | 0.4 | 23.1 | 0.4 | 23.1 | 115 |
| t _{PZH} | ŌĒ | В | 1.8 | 32 | 1.6 | 16 | 1.2 | 12.6 | 0.9 | 10.8 | ns |
| t _{PZL} | OE | В | 1.0 | 32 | 1.0 | 10 | 1.2 | 12.0 | 0.9 | 10.0 | 115 |

Switching Characteristics

over recommended operating free-air temperature range, V_{CCA} = 2.5 V \pm 0.2 V (unless otherwise noted) (see Figure 1)

| PARAMETER | FROM (INPUT) | TO (OUTPUT) | V _{CCB} = ± 0.1 | | | = 2.5 V .2 V | V _{CCB} = ± 0. | | V _{CCB} 0.5 | | UNIT |
|------------------|-----------------|-------------|--------------------------|------|-----|-----------------|-------------------------|------|-------------------------|------|------|
| | (INFOT) | (OUTPUT) | MIN | MAX | MIN | MAX | MIN | MAX | MIN | MAX | |
| t _{PLH} | A | В | 1.6 | 21.4 | 1.2 | 9 | 0.8 | 6.2 | 0.6 | 4.8 | ns |
| t _{PHL} | ^ | Б | 1.0 | 21.4 | 1.2 | | 0.0 | 0.2 | 0.0 | 4.0 | 115 |
| t _{PLH} | В | Α | 1.2 | 9.3 | 1 | 9.1 | 1 | 8.9 | 0.9 | 8.8 | ns |
| t _{PHL} | В | A | 1.2 | 9.3 | | 9.1 | 1 | 0.9 | 0.9 | 0.0 | 115 |
| t _{PHZ} | ŌĒ | A. | 1.4 | 9 | 1.4 | 9 | 1.4 | 9 | 1.4 | 9 | ns |
| t _{PLZ} | OL | A | 1.4 | 9 | 1.4 | 9 | 1.4 | 9 | 1.4 | 9 | 115 |
| t _{PHZ} | ŌĒ | В | 2.3 | 29.6 | 1.8 | 11 | 1.7 | 9.3 | 0.9 | 6.9 | ns |
| t_{PLZ} | OL | В | 2.3 | 29.0 | 1.0 | 11 | 1.7 | 9.3 | 0.9 | 0.9 | 115 |
| t _{PZH} | ŌĒ | Α | 1 | 10.9 | 1 | 10.9 | 1 | 10.9 | 1 | 10.9 | ns |
| t _{PZL} | OL . | Α | ' | 10.9 | | 10.9 | | 10.9 | | 10.9 | 115 |
| t _{PZH} | OE | В | 1.7 | 28.2 | 1.6 | 12.9 | 1.2 | 9.4 | 1 | 6.9 | ns |
| t _{PZL} | OE | В | 1.7 | 20.2 | 1.0 | 12.9 | 1.2 | 9.4 | ' | 0.9 | 115 |

SCES636A-AUGUST 2005-REVISED AUGUST 2005

Switching Characteristics

over recommended operating free-air temperature range, V_{CCA} = 3.3 V \pm 0.3 V (unless otherwise noted) (see Figure 1)

| PARAMETER | FROM (INPUT) | TO (OUTBUT) | V _{CCB} = ± 0.1 | | V _{CCB} = ± 0. | 2.5 V 2 V | V _{CCB} = ± 0.3 | | ν _{CCB} ± 0 . | | UNIT |
|------------------|-----------------|-------------|--------------------------|------|-------------------------|--------------|-----------------------------|-----|----------------------------------|-----|------|
| | (INPOT) | (OUTPUT) | MIN | MAX | MIN | MAX | MIN | MAX | MIN | MAX | |
| t _{PLH} | А | В | 1.5 | 21.2 | 1.1 | 8.8 | 0.8 | 6.1 | 0.5 | 4.4 | ns |
| t _{PHL} | | В | 1.0 | 21.2 | 1.1 | 0.0 | 0.0 | 0.1 | 0.5 | 4.4 | 113 |
| t _{PLH} | В | А | 0.9 | 7.2 | 0.8 | 6.2 | 0.7 | 6.1 | 0.6 | 6 | ns |
| t _{PHL} | | ^ | 0.9 | 1.2 | 0.0 | 0.2 | 0.7 | 0.1 | 0.0 | U | 113 |
| t _{PHZ} | ŌĒ | A | 1.6 | 8.2 | 1.6 | 8.2 | 1.6 | 6.2 | 1.6 | 8.2 | ns |
| t _{PLZ} | OL | ^ | 1.0 | 0.2 | 1.0 | 0.2 | 1.0 | 0.2 | 1.0 | 0.2 | 113 |
| t _{PHZ} | ŌĒ | В | 2.1 | 29 | 1.7 | 10.3 | 1.5 | 8.6 | 0.8 | 6.3 | ns |
| t _{PLZ} | OL | В | 2.1 | 23 | 1.7 | 10.5 | 1.5 | 0.0 | 0.0 | 0.5 | 113 |
| t _{PZH} | ŌĒ | A | 0.8 | 7.8 | 0.8 | 7.8 | 0.8 | 7.8 | 0.8 | 7.8 | ns |
| t _{PZL} | OL | ^ | 0.0 | 7.0 | 0.0 | 7.0 | 0.0 | 7.0 | 0.0 | 7.0 | 113 |
| t _{PZH} | ŌĒ | В | 1.6 | 27.7 | 1.4 | 12.4 | 1.1 | 8.5 | 0.9 | 8.4 | ns |
| t _{PZL} | OL | В | 1.0 | 21.1 | 1.4 | 12.4 | 1.1 | 0.5 | 0.9 | 0.4 | 115 |

Switching Characteristics

over recommended operating free-air temperature range, V_{CCA} = 5 V \pm 0.5 V (unless otherwise noted) (see Figure 1)

| PARAMETER | PARAMETER FROM (INPUT) | | V _{CC} = ± 0.1 | | V _{CC} = ± 0.2 | | V _{CC} = ± 0.3 | | ν _{cc} : ± 0. | | UNIT |
|------------------|------------------------|----------|-------------------------|------|-------------------------|------|----------------------------|-----|---------------------------|-----|------|
| | (INFOT) | (OUTPUT) | MIN | MAX | MIN | MAX | MIN | MAX | MIN | MAX | |
| t _{PLH} | Α | В | 1.6 | 21.4 | 1 | 8.8 | 0.7 | 6 | 0.4 | 4.2 | ns |
| t _{PHL} | A | В | 1.0 | 21.4 | | 0.0 | 0.7 | O | 0.4 | 4.2 | 115 |
| t _{PLH} | В | Α | 0.7 | 6.8 | 0.4 | 4.8 | 0.3 | 4.5 | 0.3 | 4.3 | ns |
| t _{PHL} | В | A | 0.7 | 0.0 | 0.4 | 4.0 | 0.5 | 4.5 | 0.5 | 4.5 | 113 |
| t _{PHZ} | ŌĒ | A | 0.3 | 5.4 | 0.3 | 5.4 | 0.3 | 5.4 | 0.3 | 6.4 | ns |
| t _{PLZ} | OL | A | 0.5 | 5.4 | 0.5 | 5.4 | 0.5 | 5.4 | 0.5 | 0.4 | 113 |
| t _{PHZ} | ŌĒ | В | 2 | 28.7 | 1.6 | 9.7 | 1.4 | 8 | 0.7 | 5.7 | ns |
| t _{PLZ} | OL | Б | | 20.1 | 1.0 | 3.1 | 1.4 | 0 | 0.7 | 5.1 | 113 |
| t _{PZH} | ŌĒ | Α | 0.7 | 5.5 | 0.7 | 5.5 | 0.7 | 5.5 | 0.7 | 5.5 | ns |
| t _{PZL} | OL . | A | 0.7 | 0.0 | 0.7 | 0.0 | 0.7 | 0.0 | 0.7 | 0.0 | 113 |
| t _{PZH} | ŌĒ | В | 1.6 | 27.6 | 1.3 | 11.4 | 1 | 8.1 | 0.9 | 6 | ns |
| t _{PZL} | OL . | В | 1.0 | 27.0 | 1.3 | 11.4 | ' | 0.1 | 0.9 | O | 115 |

Operating Characteristics

 $T_A = 25^{\circ}C$

| | PARAMETER | TEST CONDITIONS | V _{CCA} = V _{CCB} = 1.8 V | V _{CCA} = V _{CCB} = 2.5 V | V _{CCA} = V _{CCB} = 3.3 V | V _{CCA} = V _{CCB} = 5 V | UNIT |
|---------------------------------|-----------------------------|--|---|---|---|---|------|
| C (1) | A-port input, B-port output | | 2 | 2 | 2 | 3 | |
| C _{pdA} ⁽¹⁾ | B-port input, A-port output | $C_L = 0,$ | 18 | 19 | 19 | 22 | |
| C (1) | A-port input, B-port output | f = 10 MHz, $t_r = t_f = 1 \text{ ns}$ | 18 | 19 | 20 | 22 | pF |
| C _{pdB} ⁽¹⁾ | B-port input, A-port output | | 2 | 2 | 2 | 2 | |

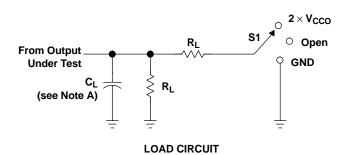
⁽¹⁾ Power dissipation capacitance per transceiver



 V_{CCA}

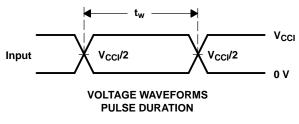
CCA/2

PARAMETER MEASUREMENT INFORMATION

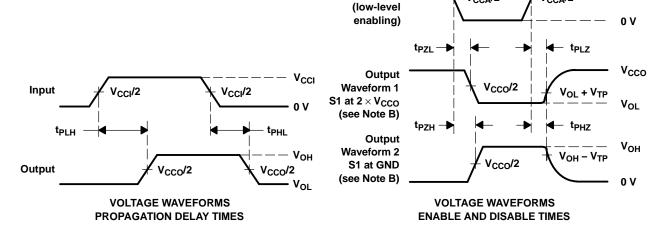


| TEST | S1 |
|------------------------------------|--------------------|
| t _{pd} | Open |
| t _{PLZ} /t _{PZL} | 2×V _{CCO} |
| t _{PHZ} /t _{PZH} | GND |

| V _{cco} | CL | R _L | V _{TP} |
|--------------------|-------|----------------|-----------------|
| 1.8 V \pm 0.15 V | 15 pF | 2 k Ω | 0.15 V |
| 2.5 V \pm 0.2 V | 15 pF | 2 k Ω | 0.15 V |
| 3.3 V \pm 0.3 V | 15 pF | 2 k Ω | 0.3 V |
| 5 V ± 0.5 V | 15 pF | 2 k Ω | 0.3 V |



V_{CCA}/2



Output Control

NOTES: A. C_L includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_0 = 50 \Omega$, $dv/dt \geq 1 V/ns$.
- D. The outputs are measured one at a time, with one transition per measurement.
- E. t_{PLZ} and t_{PHZ} are the same as t_{dis} .
- F. t_{PZL} and t_{PZH} are the same as t_{en}.
- G. t_{PLH} and t_{PHL} are the same as t_{pd} .
- H. V_{CCI} is the V_{CC} associated with the input port.
- I. V_{CCO} is the V_{CC} associated with the output port.
- J. All parameters and waveforms are not applicable to all devices.

Figure 1. Load Circuit and Voltage Waveforms





10-Jun-2014

PACKAGING INFORMATION

| Orderable Device | Status | Package Type | Package Drawing | Pins | Package Qty | Eco Plan | Lead/Ball Finish | MSL Peak Temp | Op Temp (°C) | Device Marking (4/5) | Samples |
|--------------------|--------|----------------------------|--------------------|------|----------------|----------------------------|------------------|--------------------|--------------|----------------------|---------|
| 74LVC16T245DGGRE4 | ACTIVE | TSSOP | DGG | 48 | 2000 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | -40 to 85 | LVC16T245 | Samples |
| 74LVC16T245DGGRG4 | ACTIVE | TSSOP | DGG | 48 | 2000 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | -40 to 85 | LVC16T245 | Samples |
| 74LVC16T245DGVRG4 | ACTIVE | TVSOP | DGV | 48 | 2000 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | -40 to 85 | LDT245 | Samples |
| SN74LVC16T245DGGR | ACTIVE | TSSOP | DGG | 48 | 2000 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | -40 to 85 | LVC16T245 | Samples |
| SN74LVC16T245DGVR | ACTIVE | TVSOP | DGV | 48 | 2000 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | -40 to 85 | LDT245 | Samples |
| SN74LVC16T245DGVRG | ACTIVE | TVSOP | DGV | 48 | | TBD | Call TI | Call TI | -40 to 85 | | Samples |
| SN74LVC16T245DL | ACTIVE | SSOP | DL | 48 | 25 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | -40 to 85 | LVC16T245 | Samples |
| SN74LVC16T245DLG4 | ACTIVE | SSOP | DL | 48 | 25 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | -40 to 85 | LVC16T245 | Samples |
| SN74LVC16T245DLR | ACTIVE | SSOP | DL | 48 | 1000 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | -40 to 85 | LVC16T245 | Samples |
| SN74LVC16T245GQLR | ACTIVE | BGA MICROSTAR JUNIOR | GQL | 56 | 1000 | TBD | SNPB | Level-1-240C-UNLIM | -40 to 85 | LDT245 | Samples |
| SN74LVC16T245ZQLR | ACTIVE | BGA MICROSTAR JUNIOR | ZQL | 56 | 1000 | Green (RoHS & no Sb/Br) | SNAGCU | Level-1-260C-UNLIM | -40 to 85 | NK245 | Samples |

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

TBD: The Pb-Free/Green conversion plan has not been defined.

⁽²⁾ Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.



PACKAGE OPTION ADDENDUM

10-Jun-2014

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes. **Pb-Free** (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead/Ball Finish Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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OTHER QUALIFIED VERSIONS OF SN74LVC16T245:

Enhanced Product: SN74LVC16T245-EP

NOTE: Qualified Version Definitions:

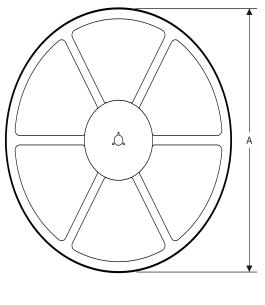
• Enhanced Product - Supports Defense, Aerospace and Medical Applications

PACKAGE MATERIALS INFORMATION

14-Jul-2012 www.ti.com

TAPE AND REEL INFORMATION

REEL DIMENSIONS





TAPE DIMENSIONS



| A0 | Dimension designed to accommodate the component width |
|----|---|
| В0 | Dimension designed to accommodate the component length |
| K0 | Dimension designed to accommodate the component thickness |
| W | Overall width of the carrier tape |
| P1 | Pitch between successive cavity centers |

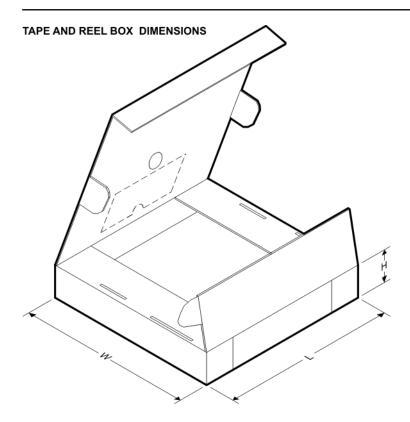
TAPE AND REEL INFORMATION

*All dimensions are nominal

| All difficults are nominal | | | | | | | | | | | | |
|----------------------------|----------------------------------|--------------------|----|------|--------------------------|--------------------------|------------|------------|------------|------------|-----------|------------------|
| Device | Package Type | Package Drawing | | SPQ | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
| SN74LVC16T245DGGR | TSSOP | DGG | 48 | 2000 | 330.0 | 24.4 | 8.6 | 15.8 | 1.8 | 12.0 | 24.0 | Q1 |
| SN74LVC16T245DGVR | TVSOP | DGV | 48 | 2000 | 330.0 | 16.4 | 7.1 | 10.2 | 1.6 | 12.0 | 16.0 | Q1 |
| SN74LVC16T245DLR | SSOP | DL | 48 | 1000 | 330.0 | 32.4 | 11.35 | 16.2 | 3.1 | 16.0 | 32.0 | Q1 |
| SN74LVC16T245GQLR | BGA MI CROSTA R JUNI OR | GQL | 56 | 1000 | 330.0 | 16.4 | 4.8 | 7.3 | 1.5 | 8.0 | 16.0 | Q1 |
| SN74LVC16T245ZQLR | BGA MI CROSTA R JUNI OR | ZQL | 56 | 1000 | 330.0 | 16.4 | 4.8 | 7.3 | 1.5 | 8.0 | 16.0 | Q1 |

PACKAGE MATERIALS INFORMATION

www.ti.com 14-Jul-2012

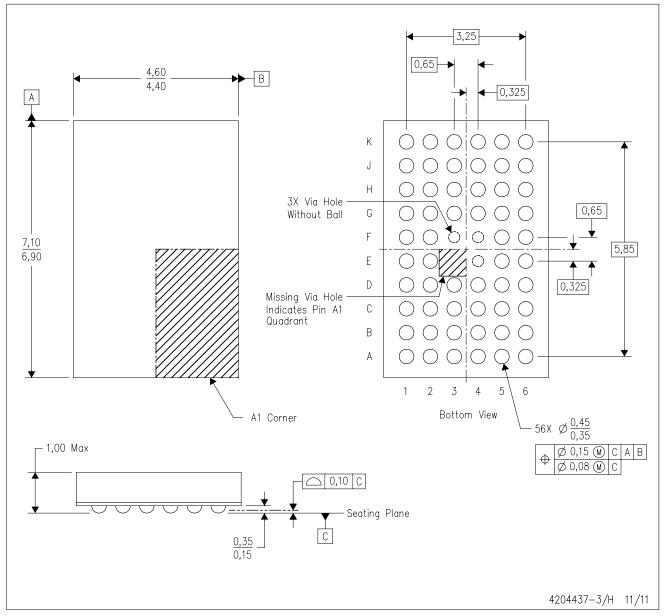


*All dimensions are nominal

| All difficultions are norminal | | | | | | | |
|--------------------------------|-------------------------|-----------------|------|------|-------------|------------|-------------|
| Device | Package Type | Package Drawing | Pins | SPQ | Length (mm) | Width (mm) | Height (mm) |
| SN74LVC16T245DGGR | TSSOP | DGG | 48 | 2000 | 367.0 | 367.0 | 45.0 |
| SN74LVC16T245DGVR | TVSOP | DGV | 48 | 2000 | 367.0 | 367.0 | 38.0 |
| SN74LVC16T245DLR | SSOP | DL | 48 | 1000 | 367.0 | 367.0 | 55.0 |
| SN74LVC16T245GQLR | BGA MICROSTAR JUNIOR | GQL | 56 | 1000 | 333.2 | 345.9 | 28.6 |
| SN74LVC16T245ZQLR | BGA MICROSTAR JUNIOR | ZQL | 56 | 1000 | 333.2 | 345.9 | 28.6 |

ZQL (R-PBGA-N56)

PLASTIC BALL GRID ARRAY



NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.

- B. This drawing is subject to change without notice.
- C. Falls within JEDEC MO-285 variation BA-2.
- D. This package is Pb-free. Refer to the 56 GQL package (drawing 4200583) for tin-lead (SnPb).

MicroStar Junior is a trademark of Texas Instruments



DL (R-PDSO-G48)

PLASTIC SMALL-OUTLINE PACKAGE



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
- D. Falls within JEDEC MO-118

PowerPAD is a trademark of Texas Instruments.



GQL (R-PBGA-N56)

PLASTIC BALL GRID ARRAY



NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.

- B. This drawing is subject to change without notice.
- C. Falls within JEDEC MO-285 variation BA-2.
- D. This package is tin-lead (SnPb). Refer to the 56 ZQL package (drawing 4204437) for lead-free.



DGG (R-PDSO-G**)

PLASTIC SMALL-OUTLINE PACKAGE

48 PINS SHOWN



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold protrusion not to exceed 0,15.

D. Falls within JEDEC MO-153

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